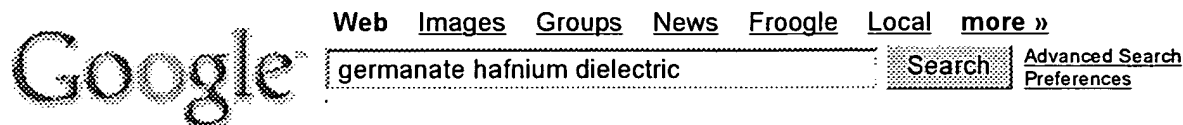


Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	307184	("257").CLAS.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:35
L2	4	transistor and (gate same dielectric same germanate)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:39
L3	1165	germanate	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:38
L4	78	3 and transistor	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:38
L5	37	transistor and (gate same dielectric same (germanate or ((germanium or ge) adj (oxide or O))))	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:55
L6	2	((("3843898") or ("4870322")).PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:47
L7	2	((("3843398") or ("4870322")).PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 11:47
L8	549	dielectric same (germanate or ((germanium or ge) near3 (oxide or O)))	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:01
L9	220	8 and gate	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:01
L10	183	9 not 5	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:01
L11	175	10 and (@ad<"20031020" or @rlad<"20031020")	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:35
L12	5	("20010023120" "6121155" "6475842" "6580118").PN. OR ("6764898").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/09 12:15

L13	4	("5112700" "5821005").PN. OR ("6437392").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/09 12:35
L14	752	(257/410).CCLS.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:35
L15	132	14 and (germanium or ge or germanate)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:37
L16	124	15 not 11	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:37
L17	118	16 and (@ad<"20031020" or @rlad<"20031020")	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:37
L18	112	17 not (germanium adj oxide)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:36
L19	48	14 and ((germanium or ge or germanate) same dielectric)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36
L20	40	19 not 11	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 12:37
L21	37	20 and (@ad<"20031020" or @rlad<"20031020")	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36
L22	7	("6383873" "6407435" "6479404").PN. OR ("6713846").URPN.	US-PGPUB; USPAT; USOCR	OR	OFF	2005/06/09 12:45
L23	2670	((438/216,287) or (257/324,e29.162)).CCLS.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:35
L24	152	23 and ((germanium or ge or germanate) same dielectric)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36
L25	148	24 and (@ad<"20031020" or @rlad<"20031020")	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36

L26	141	25 not 11	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36
L27	122	26 not 21	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:36
L28	1	("6515322").PN.	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 13:56
L29	18	(germanium adj oxide) with (dielectric adj constant)	US-PGPUB; USPAT; EPO; JPO; IBM_TDB	OR	OFF	2005/06/09 15:03



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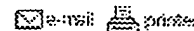
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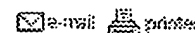
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- ☐ 5. **Atomic layer deposition of high- κ dielectric for germanium MOS applications - substrate**
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